

Title (en)
MIXED METAL-SILICON-OXIDE BARRIERS

Title (de)
MISCHMETALL-SILICIUM-OXID-BARRIEREN

Title (fr)
BARRIÈRES D'OXYDE DE MÉTAL-SILICIUM MÉLANGÉ

Publication
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Application
EP 14757288 A 20140226

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Abstract (en)
[origin: US2014242736A1] A method of forming a thin barrier film of a mixed metal-silicon-oxide is disclosed. For example, a method of forming an aluminum-silicon-oxide mixture having a refractive index of 1.8 or less comprises exposing a substrate to sequences of a non-hydroxylated silicon-containing precursor, activated oxygen species, and metal-containing precursor until a mixed metal-silicon-oxide film having a thickness of 500 Ångstroms or less is formed on the substrate.

IPC 8 full level
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CPC (source: EP US)
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C-Set (source: EP US)
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Citation (search report)
[X] US 2009130414 A1 20090521 - KIM MIN-KYUNG [KR], et al

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DOCDB simple family (publication)
US 2014242736 A1 20140828; US 9263359 B2 20160216; CN 105143501 A 20151209; CN 105143501 B 20190607; EP 2922979 A1 20150930; EP 2922979 A4 20160914; EP 2922979 B1 20201028; JP 2016515166 A 20160526; JP 6437463 B2 20181212; KR 102213047 B1 20210205; KR 20150125941 A 20151110; US 2017025635 A1 20170126; WO 2014134204 A1 20140904

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